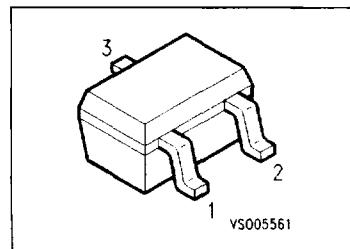


## Features

- For AF input stages and driver applications
- High current gain
- Low collector-emitter saturation voltage
- Low noise between 30 Hz and 15 kHz
- Complementary types: BC 847W, BC 848W,  
BC 849W, BC 850W (NPN)



Type	Marking	Ordering Code (tape and reel)	Pin Configuration	Package <sup>1)</sup>
			1    2    3	
BC 856 AW	3As	Q62702-C2335	B	SOT-323
BC 856 BW	3Bs	Q62702-C2292	E	
BC 857 AW	3Es	Q62702-C2293	C	
BC 857 BW	3Fs	Q62702-C2294		
BC 857 CW	3Gs	Q62702-C2295		
BC 858 AW	3Js	Q62702-C2296		
BC 858 BW	3Ks	Q62702-C2297		
BC 858 CW	3Ls	Q62702-C2298		
BC 859 AW	4As	Q62702-C2299		
BC 859 BW	4Bs	Q62702-C2300		
BC 859 CW	4Cs	Q62702-C2301		
BC 860 BW	4Fs	Q62702-C2302		
BC 860 CW	4Gs	Q62702-C2303		

<sup>1)</sup>For detailed information see chapter Package Outlines.

**Maximum Ratings**

Description	Symbol	BC 856W	BC 857W BC 860W	BC 858W BC 859W	Unit
Collector-emitter voltage	$V_{CEO}$	65	45	30	V
Collector-base voltage	$V_{CBO}$	80	50	30	V
Collector-emitter voltage	$V_{CES}$	80	50	30	V
Emitter-base voltage	$V_{EBO}$	5	5	5	V
Collector current	$I_C$		100		mA
Collector peak current	$I_{CM}$		200		mA
Total power dissipation, $T_S = 115^\circ\text{C}$	$P_{tot}$		250		mW
Junction temperature	$T_J$		150		$^\circ\text{C}$
Storage temperature range	$T_{\text{sig}}$		–65 to 150		$^\circ\text{C}$

**Thermal Resistance**

Junction - ambient <sup>1)</sup>	$R_{th JA}$	$\leq 240$	K/W
Junction - soldering point	$R_{th JS}$	$\leq 105$	K/W

**Electrical Characteristics**at  $T_A = 25^\circ\text{C}$ , unless otherwise specified.

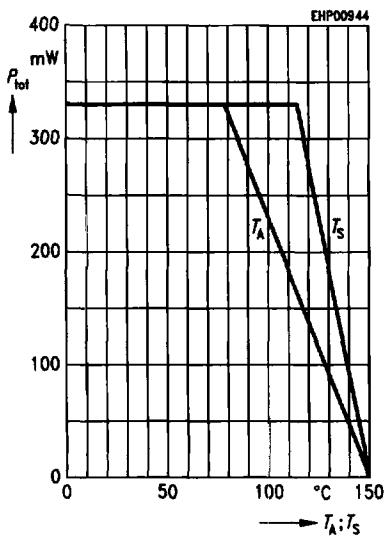
Parameter	Symbol	Values			Unit
		min.	typ.	max.	
<b>DC characteristics</b>					
Collector-emitter breakdown voltage $I_C = 10 \text{ mA}$	$V_{(BR)CE0}$	65	—	—	V
BC 856W		45	—	—	
BC 857W, BC 860W		30	—	—	
BC 858W, BC 859W					
Collector-base breakdown voltage $I_C = 10 \mu\text{A}$	$V_{(BR)CB0}$	80	—	—	
BC 856W		50	—	—	
BC 857W, BC 860W		30	—	—	
BC 858W, BC 859W					
Collector-emitter breakdown voltage $I_C = 10 \mu\text{A}, V_{BE} = 0$	$V_{(BR)CES}$	80	—	—	
BC 856W		50	—	—	
BC 857W, BC 860W		30	—	—	
BC 858W, BC 859W					
Emitter-base breakdown voltage $I_E = 1 \mu\text{A}$	$V_{(BR)EB0}$	5	—	—	
Collector cutoff current $V_{CB} = 30 \text{ V}$	$I_{CBO}$	—	—	15	nA
$V_{CB} = 30 \text{ V}, T_A = 150^\circ\text{C}$		—	—	5	$\mu\text{A}$
DC current gain $I_C = 10 \mu\text{A}, V_{CE} = 5 \text{ V}$	$h_{FE}$	—	140	—	—
BC 856 AW ... BC 859 AW		—	250	—	
BC 856 BW ... BC 860 BW		—	480	—	
BC 857 CW ... BC 860 CW					
$I_C = 2 \text{ mA}, V_{CE} = 5 \text{ V}$		125	180	250	
BC 856 AW ... BC 859 AW		220	290	475	
BC 856 BW ... BC 860 BW		420	520	800	
BC 857 CW ... BC 860 CW					
Collector-emitter saturation voltage <sup>1)</sup> $I_C = 10 \text{ mA}, I_B = 0.5 \text{ mA}$	$V_{CEsat}$	—	75	300	mV
$I_C = 100 \text{ mA}, I_B = 5 \text{ mA}$		—	250	650	
Base-emitter saturation voltage <sup>1)</sup> $I_C = 10 \text{ mA}, I_B = 0.5 \text{ mA}$	$V_{BEsat}$	—	700	—	
$I_C = 100 \text{ mA}, I_B = 5 \text{ mA}$		—	850	—	
Base-emitter voltage $I_C = 2 \text{ mA}, V_{CE} = 5 \text{ V}$	$V_{BE(on)}$	600	650	750	
$I_C = 10 \text{ mA}, V_{CE} = 5 \text{ V}$		—	—	820	

<sup>1)</sup>Pulse test:  $t \leq 300 \mu\text{s}$ ,  $D = 2\%$ .

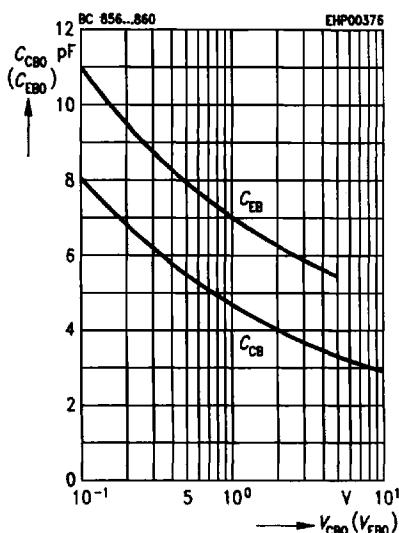
**Electrical Characteristics**at  $T_A = 25^\circ\text{C}$ , unless otherwise specified.

Parameter	Symbol	Values			Unit
		min.	typ.	max.	
<b>AC characteristics</b>					
Transition frequency $I_C = 20 \text{ mA}, V_{CE} = 5 \text{ V}, f = 100 \text{ MHz}$	$f_T$	-	250	-	MHz
Output capacitance $V_{CB} = 10 \text{ V}, f = 1 \text{ MHz}$	$C_{obo}$	-	3	-	pF
Input capacitance $V_{CB} = 0.5 \text{ V}, f = 1 \text{ MHz}$	$C_{ibo}$	-	10	-	
Short-circuit input impedance $I_C = 2 \text{ mA}, V_{CE} = 5 \text{ V}, f = 1 \text{ kHz}$ BC 856 AW ... BC 859 AW BC 856 BW ... BC 860 BW BC 857 CW ... BC 860 CW	$h_{11e}$	-	2.7	-	kΩ
-		-	4.5	-	
-		-	8.7	-	
Open-circuit reverse voltage transfer ratio $I_C = 2 \text{ mA}, V_{CE} = 5 \text{ V}, f = 1 \text{ kHz}$ BC 856 AW ... BC 859 AW BC 856 BW ... BC 860 BW BC 857 CW ... BC 860 CW	$h_{12e}$	-	1.5	-	$10^{-4}$
-		-	2.0	-	
-		-	3.0	-	
Short-circuit forward current transfer ratio $I_C = 2 \text{ mA}, V_{CE} = 5 \text{ V}, f = 1 \text{ kHz}$ BC 856 AW ... BC 859 AW BC 856 BW ... BC 860 BW BC 857 CW ... BC 860 CW	$h_{21e}$	-	200	-	-
-		-	330	-	
-		-	600	-	
Open-circuit output admittance $I_C = 2 \text{ mA}, V_{CE} = 5 \text{ V}, f = 1 \text{ kHz}$ BC 856 AW ... BC 859 AW BC 856 BW ... BC 860 BW BC 857 CW ... BC 860 CW	$h_{22e}$	-	18	-	μS
-		-	30	-	
-		-	60	-	
Noise figure $I_C = 0.2 \text{ mA}, V_{CE} = 5 \text{ V}, R_S = 2 \text{ kΩ}$ $f = 30 \text{ Hz} \dots 15 \text{ kHz}$ BC 859W BC 860W $f = 1 \text{ kHz}, \Delta f = 200 \text{ Hz}$ BC 859W BC 860W	$F$	-	1.2	4	dB
-		-	1.0	3	
-		-	1.0	4	
-		-	1.0	4	
Equivalent noise voltage $I_C = 0.2 \text{ mA}, V_{CE} = 5 \text{ V}, R_S = 2 \text{ kΩ}$ $f = 10 \text{ Hz} \dots 50 \text{ Hz}$ BC 860W	$V_n$	-	-	0.110	μV

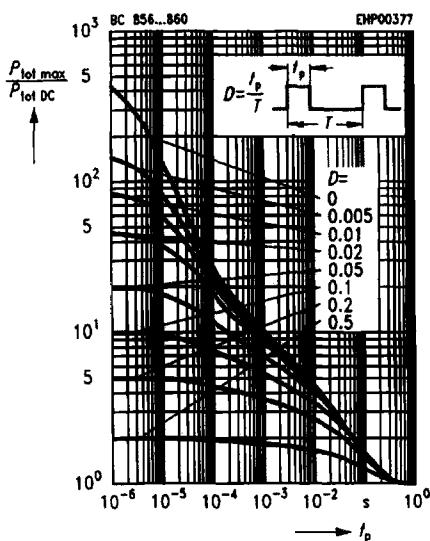
**Total power dissipation**  $P_{\text{tot}} = f(T_A^*, T_S)$   
 \* Package mounted on epoxy



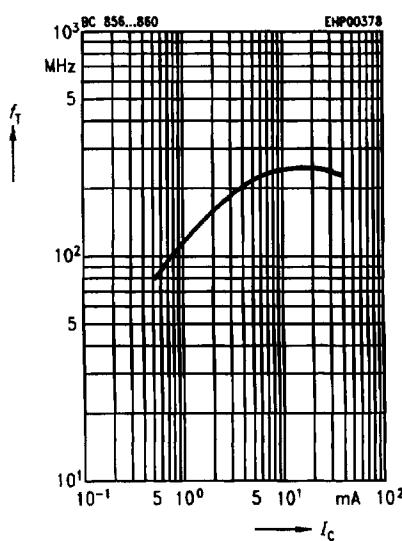
**Collector-base capacitance**  $C_{CBO} = f(V_{CBO})$   
**Emitter-base capacitance**  $C_{EBO} = f(V_{EBO})$



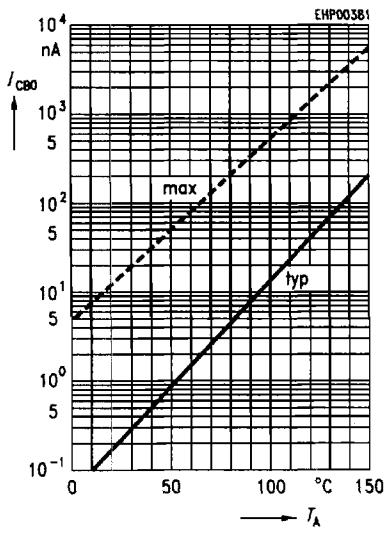
**Permissible pulse load**  $P_{\text{tot max}}/P_{\text{tot DC}} = f(t_p)$



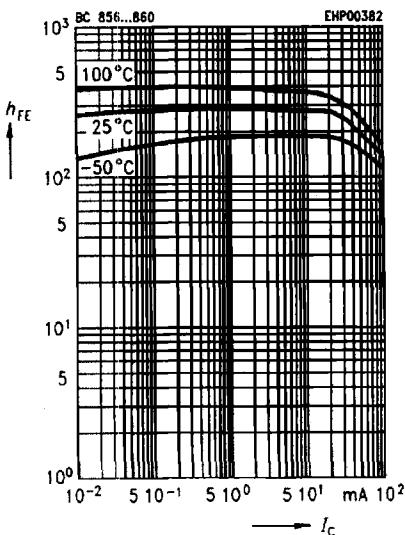
**Transition frequency**  $f_T = f(I_c)$   
 $V_{CE} = 5 \text{ V}$



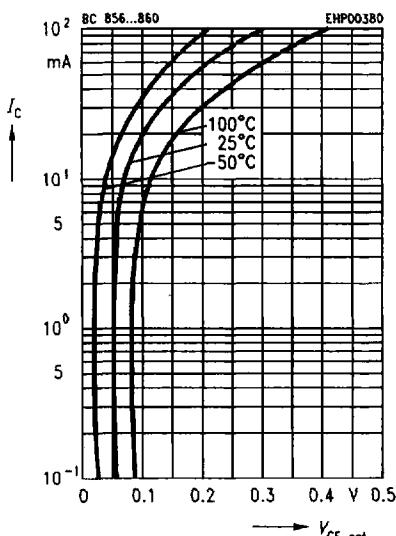
**Collector cutoff current**  $I_{CBO} = f(T_A)$   
 $V_{CB} = 30 \text{ V}$



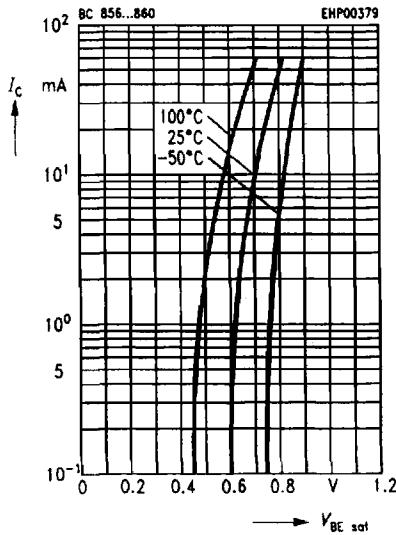
**DC current gain**  $h_{FE} = f(I_C)$   
 $V_{CE} = 5 \text{ V}$



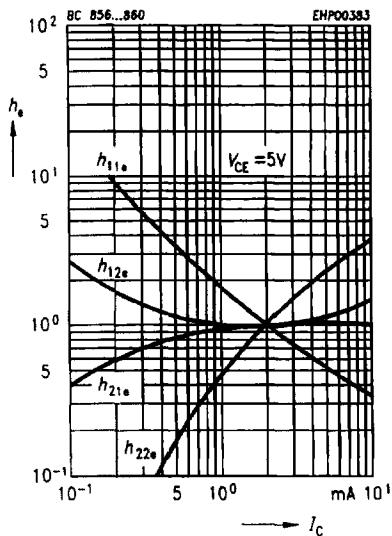
**Collector-emitter saturation voltage**  
 $I_C = f(V_{CEsat})$ ,  $h_{FE} = 20$



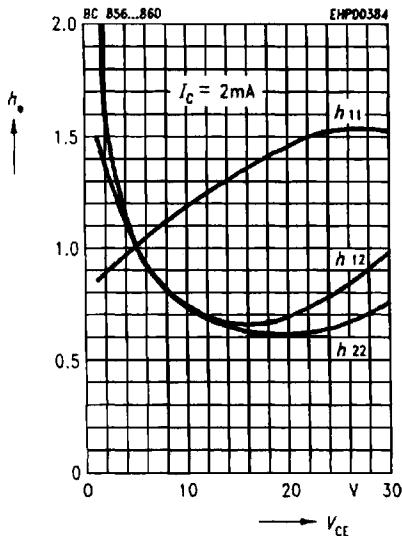
**Base-emitter saturation voltage**  
 $I_C = f(V_{BESat})$ ,  $h_{FE} = 20$



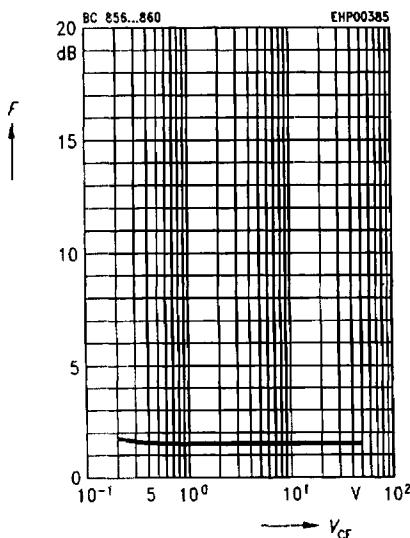
**h parameter  $h_{\text{e}} = f(I_{\text{C}})$  normalized**  
 $V_{\text{CE}} = 5 \text{ V}$



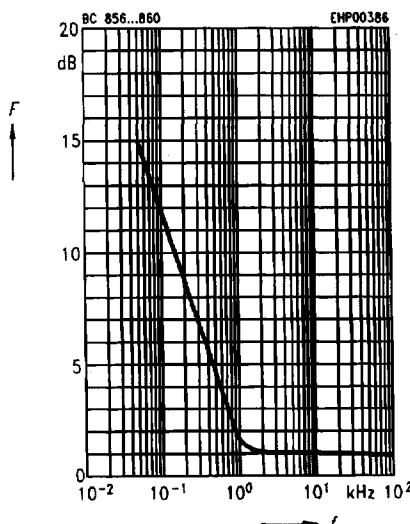
**h parameter  $h_{\text{e}} = f(V_{\text{CE}})$  normalized**  
 $I_{\text{C}} = 2 \text{ mA}$

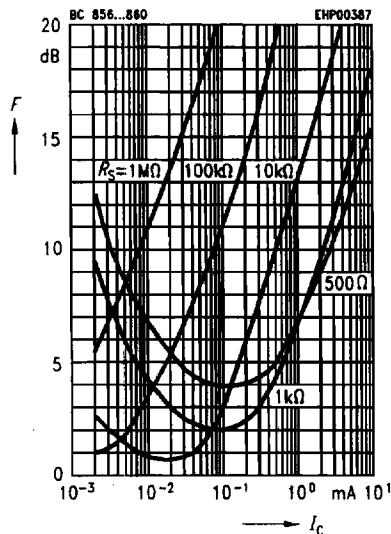
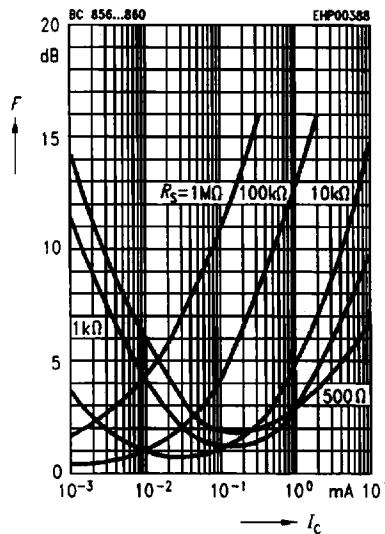


**Noise figure  $F = f(V_{\text{CE}})$**   
 $I_{\text{C}} = 0.2 \text{ mA}$ ,  $R_s = 2 \text{ k}\Omega$ ,  $f = 1 \text{ kHz}$



**Noise figure  $F = f(f)$**   
 $I_{\text{C}} = 0.2 \text{ mA}$ ,  $V_{\text{CE}} = 5 \text{ V}$ ,  $R_s = 2 \text{ k}\Omega$



**Noise figure  $F = f(I_c)$**  $V_{CE} = 5 \text{ V}, f = 120 \text{ Hz}$ **Noise figure  $F = f(I_c)$**  $V_{CE} = 5 \text{ V}, f = 1 \text{ kHz}$ **Noise figure  $F = f(I_c)$**  $V_{CE} = 5 \text{ V}, f = 10 \text{ kHz}$ 